

Trans JFET P-CH

Manufacturer:	Solitron Devices Inc
Package/Case:	CAN
Product Type:	Thyristors
Lifecycle:	Active



Images are for reference only

[Inquiry](#)

General Description

2N5116 is a type of transistor that falls under the category of NPN RF (Radio Frequency) transistors.

Key Features

- Maximum power dissipation of 600mW
- Maximum collector-base voltage of 50V
- Maximum collector current of 100mA
- Frequency range up to 1 GHz
- Low noise figure
- High gain and high input impedance

Application

- RF amplifier circuits in communication systems, such as mobile phones, radios, and televisions
- Oscillator circuits
- Mixer circuits
- Signal generators
- Ham radio circuits

